NSN 5962-01-481-3808

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-481-3808 **Body Length:** 1.490 inches **Body Width:** 0.610 inches **Body Height:** 0.232 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** 1430-01-131-5427 **Features Provided:** Monolithic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Product Name:** Microcircuit, digital, memory, cmos, parallel 512 x 9 fifo, monolithic silicon **Voltage Rating And Type Per Characteristic:** -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 65.00 nanoseconds af output megawatts **Memory Device Type:** First-in first-out **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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